

300-MHz, 2.5-Ω, Dual SPDT Analog Switches

DESCRIPTION

The DG787 are dual SPDT analog switches which operate from 1.8 V to 5.5 V single rail power supply. They are design for audio, video, and USB switching applications.

The devices have 2.5 Ω on-resistance and 300 MHz 3 dB bandwidth. 0.2 Ω on-resistance matching and 1 Ω flatness make the device high linearity. The devices are 1.6 V logic compatible within the full operation voltage range.

These switches are built on a sub-micron high density process that brings low power consumption and low voltage performance.

The switch is package in MSOP 10 package.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG787 is offered in a MSOP package. The MSOP package uses 100 % matte tin device termination and is represented by the lead (Pb)-free “-E3” suffix. Both the matte tin device terminations meet all JEDEC standards for reflow and MSL ratings.

FEATURES

- 1.8 V to 5.5 V operation
- 2.5 Ω at 2.7 V R_{ON}
- 300 MHz - 3 dB bandwidth
- ESD per MIL-STD-883 method 3015.7 > 2 kV
- Latch-up current 200 mA (JESD 78)
- 1.6 V logic compatible
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition



RoHS
COMPLIANT
HALOGEN
FREE

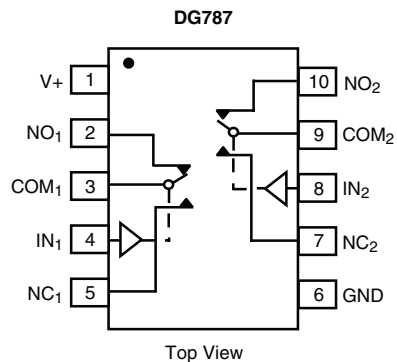
BENEFITS

- Space saving MSOP-10 package
- High linearity
- Low power consumption
- High bandwidth
- Full rail signal swing range

APPLICATIONS

- Cellular phones
- MP3
- Media players
- Modems
- Hard drives
- PCMCIA

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE		
Logic	NC1 and NC2	NO1 and NO2
0	ON	OFF
1	OFF	ON

ORDERING INFORMATION		
Temp. Range	Package	Part Number
- 40 °C to 85 °C	MSOP-10	DG787DQ-T1-E3



ABSOLUTE MAXIMUM RATINGS			
Parameter		Limit	Unit
Reference V+ to GND		- 0.3 to + 6	V
IN, COM, NC, NO ^a		- 0.3 to (V+ + 0.3)	
Continuous Current (NO, NC, COM)		± 100	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 500	
Storage Temperature	(D Suffix)	- 65 to 150	°C
ESD per MIL-STD-883 Method 3015.7		> 2	kV
Power Dissipation (Packages) ^c	MSOP-10 ^d	320	mW

Notes:

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. Refer to IPC/JEDEC (J-STD-020).
- c. All leads welded or soldered to PC board.
- d. Derate 4.0 mW/°C above 70 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS V+ = 3 V							
Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 2.7 V to 3.6 V, V _{IN} = 0.5 V or 1.4 V ^e	Temp. ^a	Limits - 40 °C to 85 °C			Unit
				Min. ^b	Typ. ^c	Max. ^b	
Analog Switch							
Analog Signal Range ^d	V _{NO} , V _{NC} , V _{COM}		Full	0		V+	V
On-Resistance ^d	R _{ON}	V+ = 2.7 V I _{NO} , I _{NC} = 10 mA	Room Full		2.5	3.5 3.8	Ω
R _{ON} Flatness ^d	R _{ON} Flatness		Room		0.52	1.0	
On-Resistance Match Between Channels ^d	ΔR _{DS(on)}		Room			0.25	
Switch Off Leakage Current	I _{NO(off)} I _{NC(off)}	V+ = 3.3 V, V _{NO} , V _{NC} = 0.3 V/3 V, V _{COM} = 3 V/0.3 V	Room Full	- 1 - 20		1 20	nA
	I _{COM(off)}		Room Full	- 1 - 20		1 20	
Channel-On Leakage Current	I _{COM(on)}	V+ = 3.3 V, V _{NO} , V _{NC} = V _{COM} = 0.3 V/3 V	Room Full	- 1 - 20		1 20	
Digital Control							
Input High Voltage ^d	V _{INH}		Full	1.4			V
Input Low Voltage	V _{INL}		Full			0.5	
Input Capacitance	C _{in}		Full		5		pF
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+	Full	1		1	μA



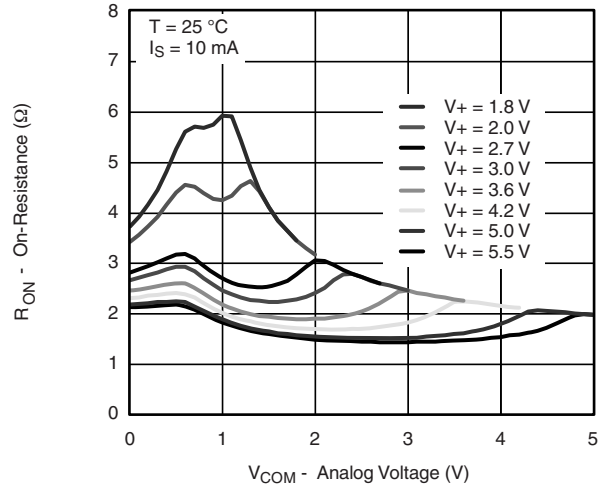
SPECIFICATIONS $V_+ = 3\text{ V}$							
Parameter	Symbol	Test Conditions Otherwise Unless Specified $V_+ = 2.7\text{ V to } 3.6\text{ V}, V_{IN} = 0.5\text{ V or } 1.4\text{ V}^e$	Temp. ^a	Limits - 40 °C to 85 °C			Unit
				Min. ^b	Typ. ^c	Max. ^b	
Dynamic Characteristics							
Turn-On Time	t_{ON}	$V_+ = 2.7\text{ V}, V_{NO} \text{ or } V_{NC} = 1.5\text{ V}$ $R_L = 300\ \Omega, C_L = 35\text{ pF}$	Room Full		21	51	ns
Turn-Off Time	t_{OFF}		Room Full		15	45	
Break-Before-Make Time	t_d		Full	1		46	
Charge Injection ^d	Q_{INJ}	$C_L = 1\text{ nF}, V_{GEN} = 2.0\text{ V}, R_{GEN} = 0\ \Omega$	Room		1		pC
Off-Isolation ^d	OIRR	$R_L = 50\ \Omega, C_L = 5\text{ pF}$	f = 1 MHz	Room		- 74	dB
			f = 10 MHz	Room		- 54	
Crosstalk ^d	X_{TALK}		f = 1 MHz	Room		- 76	
			f = 10 MHz	Room		- 56	
N_O, N_C Off Capacitance ^d	$C_{NO(off)}$	$V_{IN} = 0 \text{ or } V_+, f = 1\text{ MHz}$	Room		12		pF
	$C_{NC(off)}$		Room		12		
Channel-On Capacitance ^d	$C_{NO(on)}$		Room		40		
	$C_{NC(on)}$		Room		40		
Power Supply							
Power Supply Current	I_+	$V_{IN} = 0 \text{ or } V_+$	Room Full			1.0 1.0	μA

SPECIFICATIONS $V_+ = 5\text{ V}$							
Parameter	Symbol	Test Conditions Otherwise Unless Specified $V_+ = 4.2\text{ V to } 5.5\text{ V}, V_{IN} = 0.8\text{ V or } 2.0\text{ V}^e$	Temp. ^a	Limits - 40 °C to 85 °C			Unit
				Min. ^b	Typ. ^c	Max. ^b	
Analog Switch							
Analog Signal Range ^d	V_{NO}, V_{NC}, V_{COM}		Full	0		V_+	V
On-Resistance ^d	R_{ON}	$V_+ = 4.2\text{ V}$ $I_{NO}, I_{NC} = 10\text{ mA}$	Room Full		2.2	2.9 3.1	Ω
R_{ON} Flatness ^d	R_{ON} Flatness		Room		0.53	1.0	
On-Resistance Match Between Channels ^d	$\Delta R_{DS(on)}$		Room			0.25	
Switch Off Leakage Current	$I_{NO(off)}$ $I_{NC(off)}$	$V_+ = 5.5\text{ V},$ $V_{NO}, V_{NC} = 1\text{ V/4.5 V}, V_{COM} = 4.5\text{ V/1 V}$	Room Full	- 1 - 20		1 20	nA
	$I_{COM(off)}$		Room Full	- 1 - 20		1 20	
Channel-On Leakage Current	$I_{COM(on)}$	$V_+ = 5.5\text{ V}, V_{NO}, V_{NC} = V_{COM} = 1\text{ V/4.5 V}$	Room Full	- 1 - 20		1 20	
Digital Control							
Input High Voltage ^d	V_{INH}		Full	2.0			V
Input Low Voltage	V_{INL}		Full			0.8	
Input Capacitance	C_{in}		Full		5		pF
Input Current	I_{INL} or I_{INH}	$V_{IN} = 0$ or V_+	Full	1		1	μA
Dynamic Characteristics							
Turn-On Time	t_{ON}	$V_+ = 4.2\text{ V}, V_{NO}$ or $V_{NC} = 3.0\text{ V}$ $R_L = 300\ \Omega, C_L = 35\text{ pF}$	Room Full		15	45 46	ns
Turn-Off Time	t_{OFF}		Room Full		12	42 43	
Break-Before-Make Time	t_d		Full	1			
Charge Injection ^d	Q_{INJ}	$C_L = 1\text{ nF}, V_{GEN} = 2.0\text{ V}, R_{GEN} = 0\ \Omega$	Room		1		pC
Off-Isolation ^d	OIRR	$R_L = 50\ \Omega, C_L = 5\text{ pF}$	Room		f = 1 MHz	- 74	dB
Crosstalk ^d	X_{TALK}		Room		f = 10 MHz	- 54	
			Room		f = 1 MHz	- 78	
			Room		f = 10 MHz	- 56	
N_O, N_C Off Capacitance ^d	$C_{NO(off)}$	$V_{IN} = 0$ or $V_+, f = 1\text{ MHz}$	Room		12		pF
	$C_{NC(off)}$		Room		12		
Channel-On Capacitance ^d	$C_{NO(on)}$		Room		40		
	$C_{NC(on)}$		Room		40		
Power Supply							
Power Supply Current	I_+	$V_{IN} = 0$ or V_+	Room Full			1.0 1.0	μA

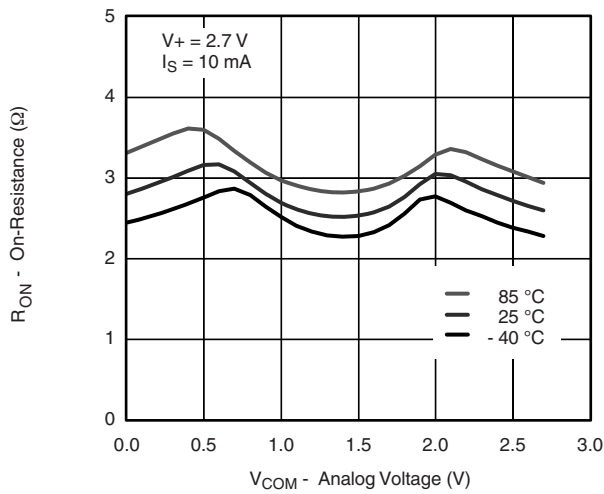
Notes:

- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. Typical values are for design aid only, not guaranteed nor subject to production testing.
- c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- d. Guarantee by design, nor subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Guaranteed by 5 V testing, not production tested.

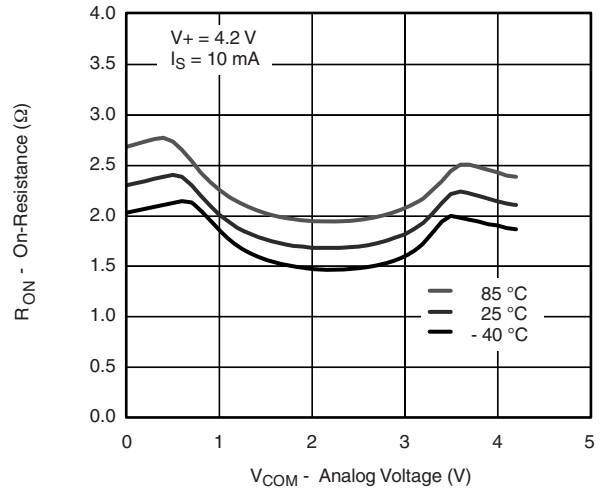
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



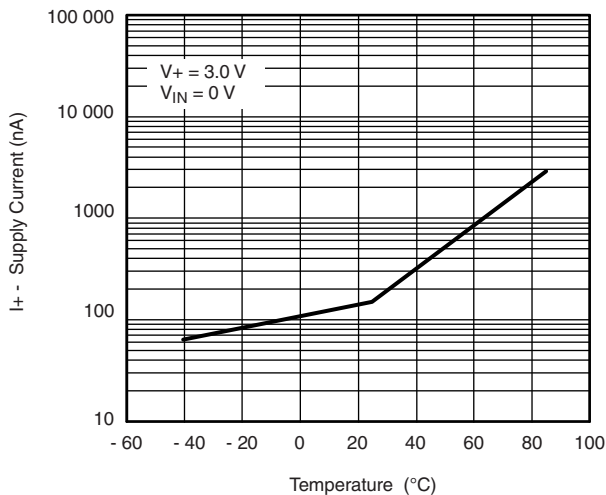
RON vs. VCOM and Single Supply Voltage



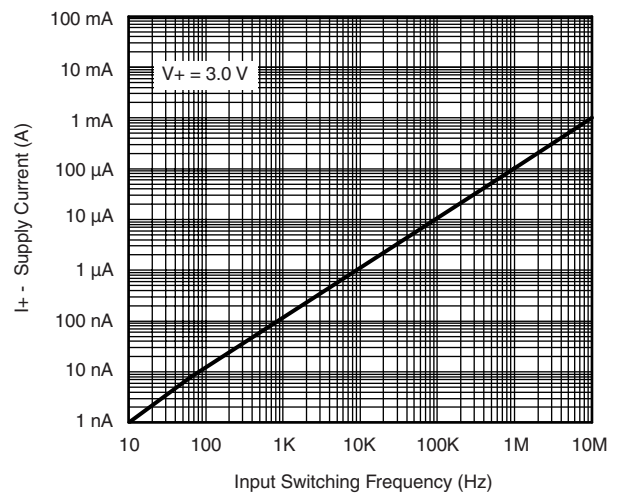
RON vs. Analog Voltage and Temperature



RON vs. Analog Voltage and Temperature

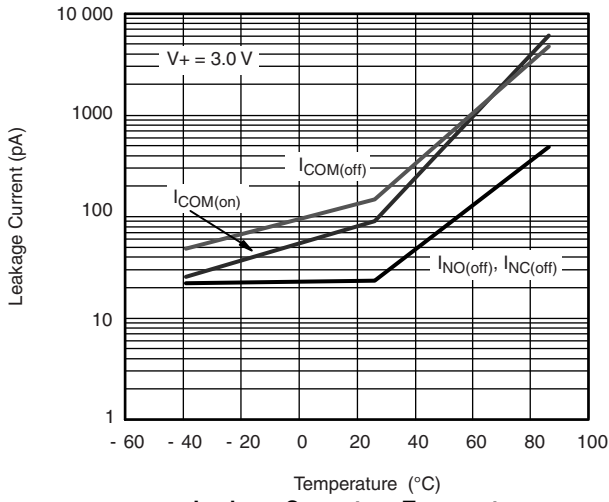


Supply Current vs. Temperature

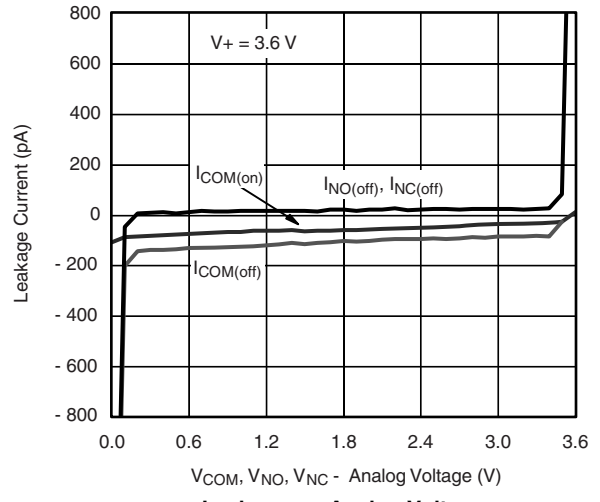


Supply Current vs. Input Switching Frequency

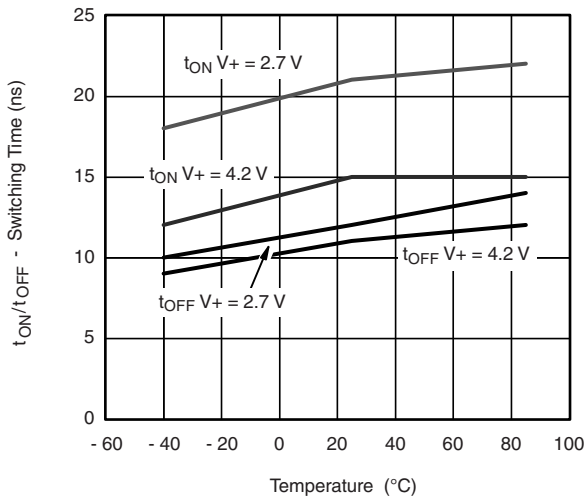
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



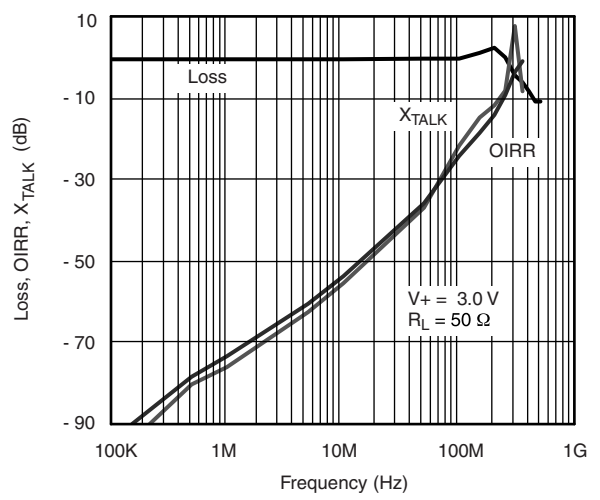
Leakage Current vs. Temperature



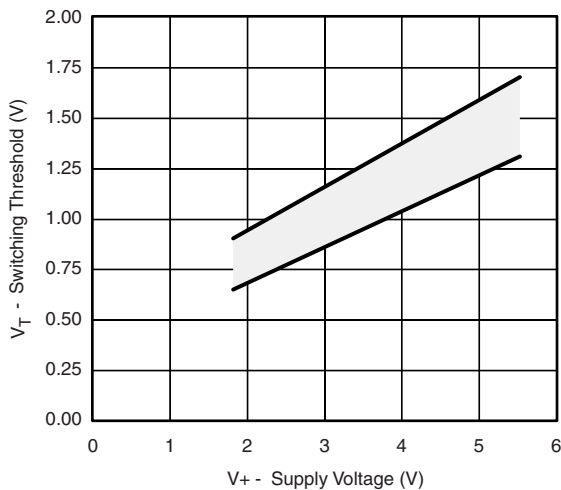
Leakage vs. Analog Voltage



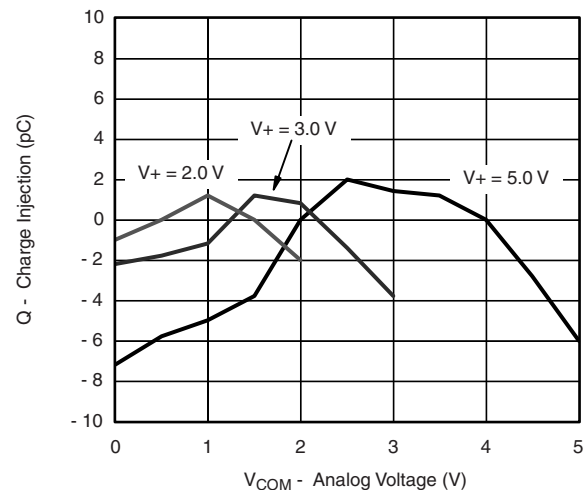
Switching Time vs. Temperature



Insertion Loss, Off-Isolation Crosstalk vs. Frequency

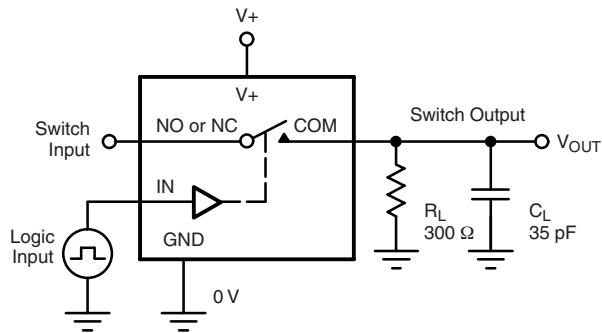


Switching Threshold vs. Supply Voltage



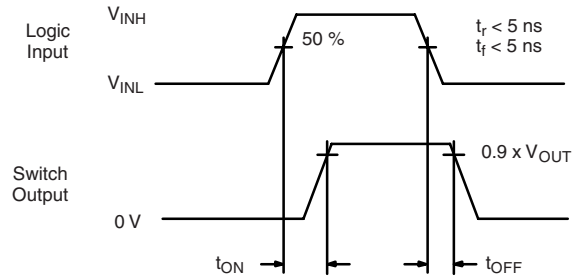
Charge Injection vs. Analog Voltage

TEST CIRCUITS



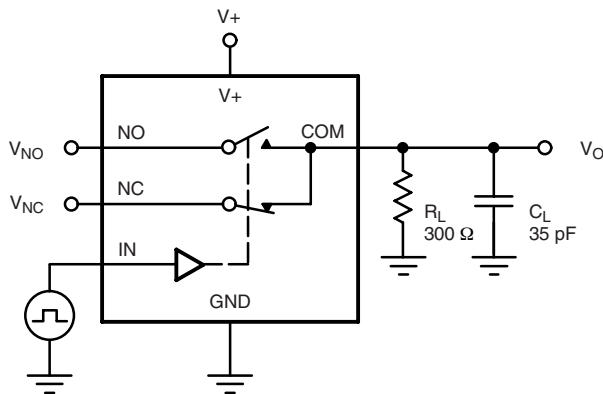
C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time



C_L (includes fixture and stray capacitance)

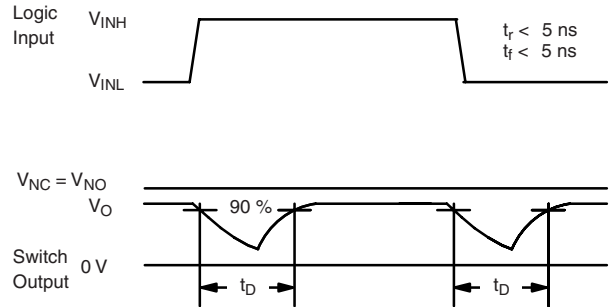
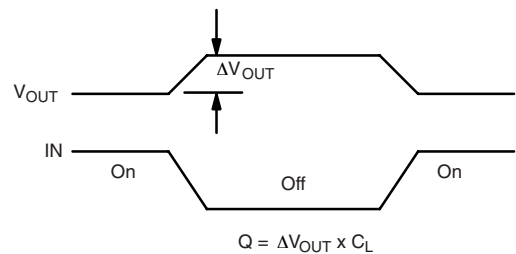
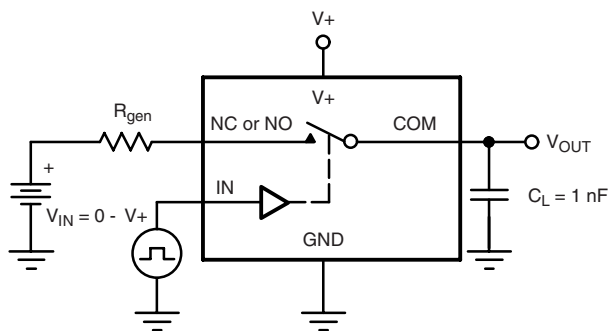


Figure 2. Break-Before-Make Interval



IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

TEST CIRCUITS

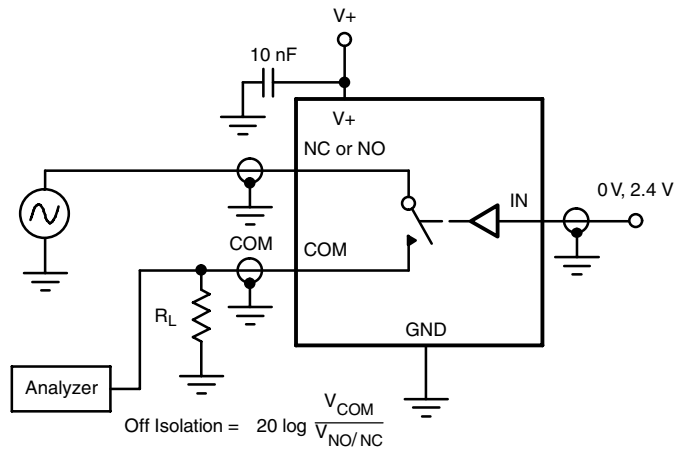


Figure 4. Off-Isolation

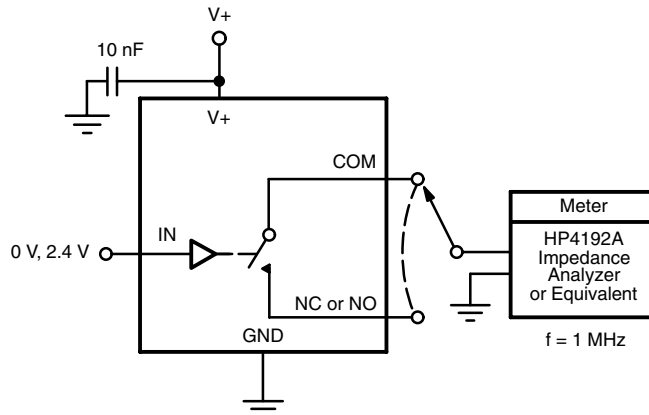


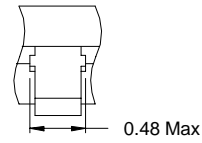
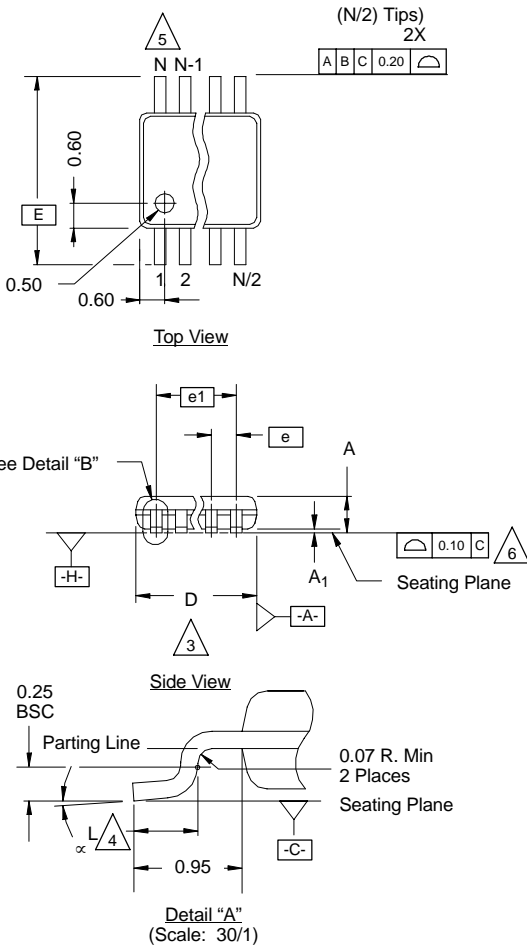
Figure 5. Channel Off/On Capacitance

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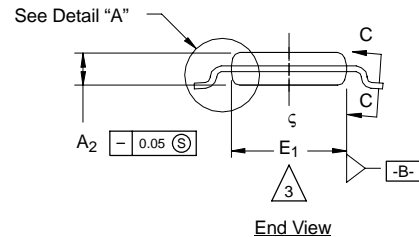
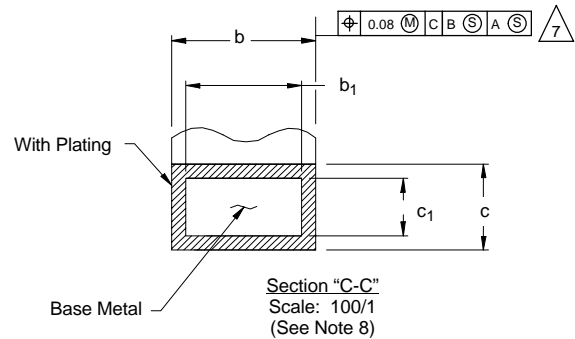


MSOP: 10-LEADS

JEDEC Part Number: MO-187, (Variation AA and BA)



Detail "B"
(Scale: 30/1)
Dambar Protrusion



NOTES:

- Die thickness allowable is 0.203 ± 0.0127 .
- Dimensioning and tolerances per ANSI.Y14.5M-1994.
- Dimensions "D" and "E₁" do not include mold flash or protrusions, and are measured at Datum plane [-H-], mold flash or protrusions shall not exceed 0.15 mm per side.
- Dimension is the length of terminal for soldering to a substrate.
- Terminal positions are shown for reference only.
- Formed leads shall be planar with respect to one another within 0.10 mm at seating plane.
- The lead width dimension does not include Dambar protrusion. Allowable Dambar protrusion shall be 0.08 mm total in excess of the lead width dimension at maximum material condition. Dambar cannot be located on the lower radius or the lead foot. Minimum space between protrusions and an adjacent lead to be 0.14 mm. See detail "B" and Section "C-C".
- Section "C-C" to be determined at 0.10 mm to 0.25 mm from the lead tip.
- Controlling dimension: millimeters.
- This part is compliant with JEDEC registration MO-187, variation AA and BA.
- Datums [-A-] and [-B-] to be determined Datum plane [-H-].
- Exposed pad area in bottom side is the same as teh leadframe pad size.

N = 10L

Dim	MILLIMETERS			Note
	Min	Nom	Max	
A	-	-	1.10	
A ₁	0.05	0.10	0.15	
A ₂	0.75	0.85	0.95	
b	0.17	-	0.27	8
b ₁	0.17	0.20	0.23	8
c	0.13	-	0.23	
c ₁	0.13	0.15	0.18	
D	3.00 BSC			3
E	4.90 BSC			
E ₁	2.90	3.00	3.10	3
e	0.50 BSC			
e ₁	2.00 BSC			
L	0.40	0.55	0.70	4
N	10			5
α	0°	4°	6°	
ECN: T-02080—Rev. C, 15-Jul-02 DWG: 5867				



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